



STPS10H100CT/CG/CR/CFP

HIGH VOLTAGE POWER SCHOTTKY RECTIFIER

MAIN PRODUCT CHARACTERISTICS

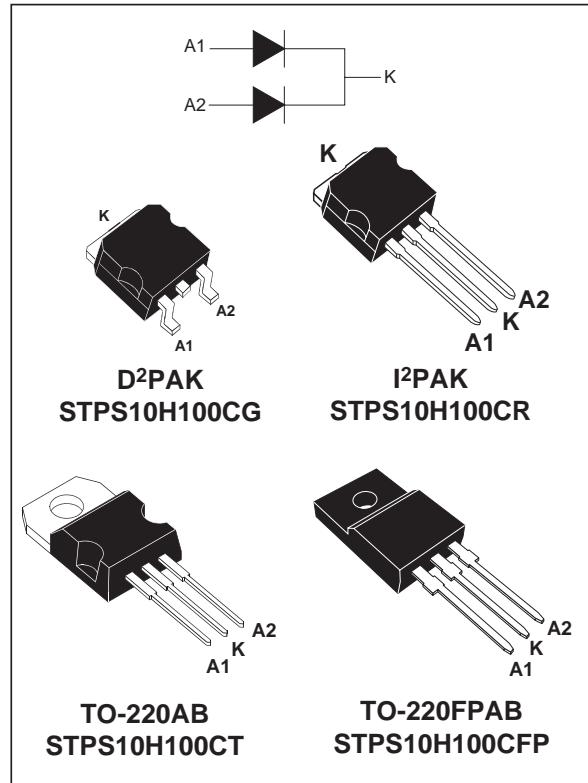
| | |
|-------------|---------|
| $I_{F(AV)}$ | 2 x 5 A |
| V_{RRM} | 100 V |
| T_j | 175°C |
| V_F (max) | 0.61 V |

FEATURES AND BENEFITS

- HIGH JUNCTION TEMPERATURE CAPABILITY FOR CONVERTERS LOCATED IN CONFINED ENVIRONMENT
- LOW LEAKAGE CURRENT AT HIGH TEMPERATURE
- LOW STATIC AND DYNAMIC LOSSES AS A RESULT OF THE SCHOTTKY BARRIER
- AVALANCHE CAPABILITY SPECIFIED

DESCRIPTION

Schottky barrier rectifier designed for high frequency miniature Switched Mode Power Supplies such as adaptors and on board DC/DC converters. Packaged in TO-220AB, TO-220FPAB, D²PAK and I²PAK.



ABSOLUTE RATINGS (limiting values, per diode)

| Symbol | Parameter | | | | Value | Unit | | | |
|--------------|--|---|---|-------------------------|---------------|------|--|--|--|
| V_{RRM} | Repetitive peak reverse voltage | | | | 100 | V | | | |
| $I_{F(RMS)}$ | RMS forward current | | | | 10 | A | | | |
| $I_{F(AV)}$ | Average forward current $\delta = 0.5$ | TO-220AB D ² PAK / I ² PAK | $T_c = 165^\circ\text{C}$ | per diode per device | 5 | A | | | |
| | | TO-220FPAB | $T_c = 160^\circ\text{C}$ | | 10 | A | | | |
| I_{FSM} | Surge non repetitive forward current | | $t_p = 10 \text{ ms sinusoidal}$ | | 180 | A | | | |
| I_{RRM} | Repetitive peak reverse current | | $t_p = 2 \mu\text{s square } F = 1\text{kHz}$ | | 1 | A | | | |
| P_{ARM} | Repetitive peak avalanche power | | $t_p = 1\mu\text{s } T_j = 25^\circ\text{C}$ | | 7200 | W | | | |
| T_{stg} | Storage temperature range | | | | - 65 to + 175 | °C | | | |
| T_j | Maximum operating junction temperature * | | | | 175 | °C | | | |
| dV/dt | Critical rate of rise of reverse voltage | | | | 10000 | V/μs | | | |

* : $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th}(j - a)}$ thermal runaway condition for a diode on its own heatsink

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THERMAL RESISTANCES

| Symbol | Parameter | | | Value | Unit |
|---------------|------------------|---------------------------|-----------|-------|------|
| $R_{th(j-c)}$ | Junction to case | D2PAK / I2PAK TO-220AB | Per diode | 2.2 | °C/W |
| | | | Total | 1.3 | |
| | | | Coupling | 0.3 | |
| $R_{th(c)}$ | Junction to case | TO-220FPAB | Per diode | 4.5 | °C/W |
| | | | Total | 3.5 | |
| | | | Coupling | 2.5 | |

When the diodes 1 and 2 are used simultaneously :

$$\Delta T_j(\text{diode 1}) = P(\text{diode 1}) \times R_{th(j-c)}(\text{Per diode}) + P(\text{diode 2}) \times R_{th(c)}$$

STATIC ELECTRICAL CHARACTERISTICS (per diode)

| Symbol | Parameter | Tests conditions | | Min. | Typ. | Max. | Unit |
|----------|-------------------------|---------------------------|----------------------|------|------|------|---------------|
| I_R * | Reverse leakage current | $T_j = 25^\circ\text{C}$ | $V_R = V_{RRM}$ | | | 3.5 | μA |
| | | $T_j = 125^\circ\text{C}$ | | | 1.3 | 4.5 | mA |
| V_F ** | Forward voltage drop | $T_j = 25^\circ\text{C}$ | $I_F = 5 \text{ A}$ | | | 0.73 | V |
| | | $T_j = 125^\circ\text{C}$ | | | 0.57 | 0.61 | |
| | | $T_j = 25^\circ\text{C}$ | $I_F = 10 \text{ A}$ | | | 0.85 | |
| | | $T_j = 125^\circ\text{C}$ | | | 0.66 | 0.71 | |

Pulse test : * $t_p = 5 \text{ ms}, \delta < 2\%$

** $t_p = 380 \text{ } \mu\text{s}, \delta < 2\%$

To evaluate the maximum conduction losses use the following equation :

$$P = 0.51 \times I_{F(\text{AV})} + 0.02 \times I_{F(\text{RMS})}^2$$

Fig. 1: Average forward power dissipation versus average forward current (per diode).

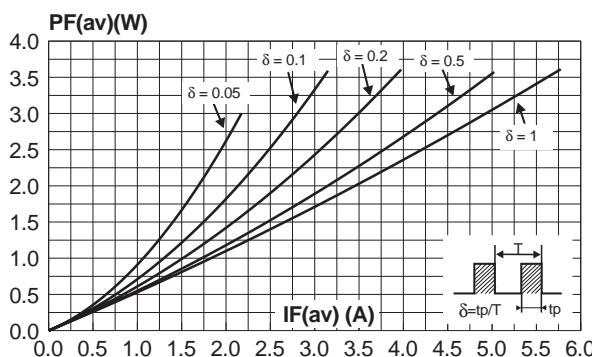


Fig. 2: Average forward current versus ambient temperature ($\delta=0.5$, per diode).

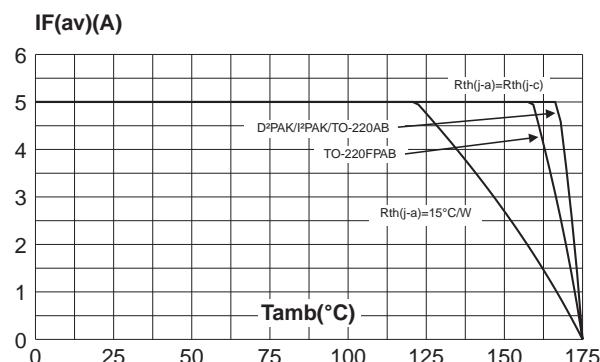


Fig. 3: Normalized avalanche power derating versus pulse duration.

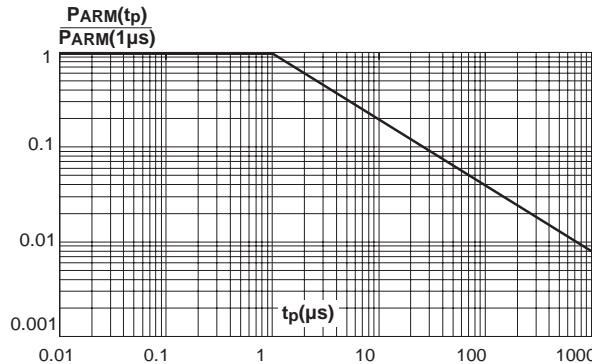


Fig. 5-1: Non repetitive surge peak forward current versus overload duration (maximum values, per diode)

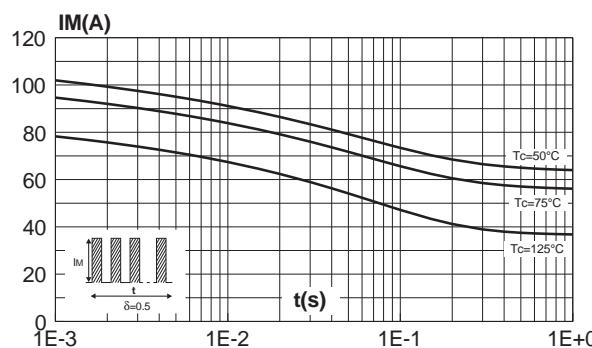


Fig. 6-1: Relative variation of thermal impedance junction to case versus pulse duration (per diode).

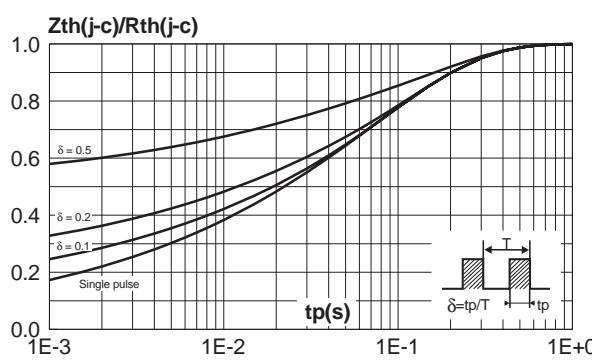


Fig. 4: Normalized avalanche power derating versus junction temperature.

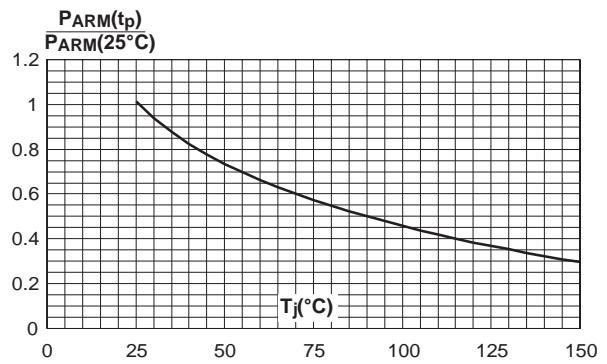


Fig. 5-2: Non repetitive surge peak forward current versus overload duration (maximum values, per diode)(TO-220FPAB)

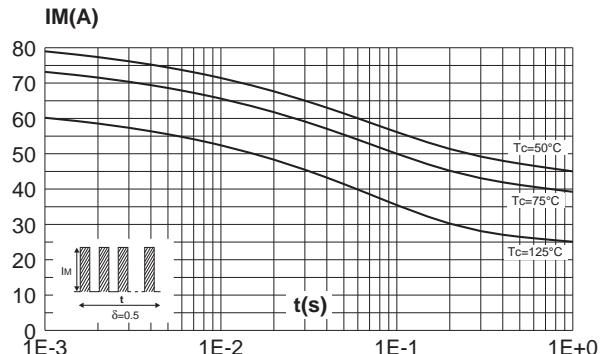
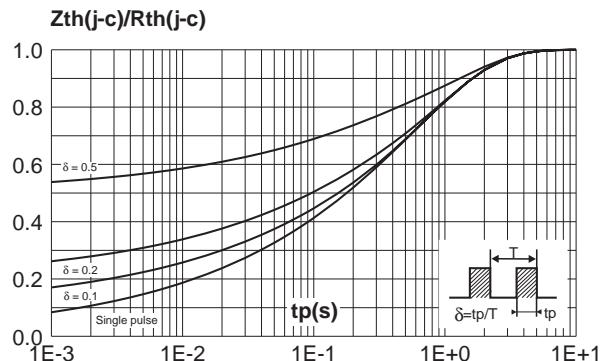


Fig. 6-2: Relative variation of thermal impedance junction to case versus pulse duration (per diode).(TO-220FPAB)



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Fig. 7: Reverse leakage current versus reverse voltage applied (typical values, per diode).

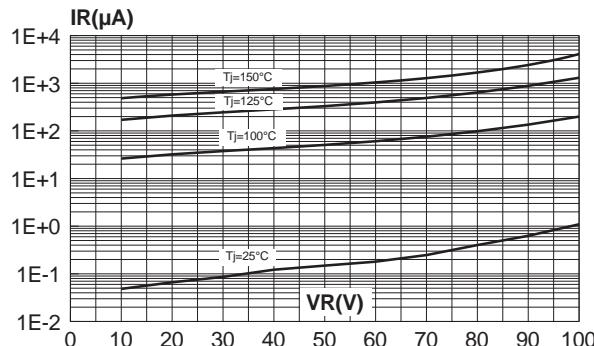


Fig. 8: Junction capacitance versus reverse voltage applied (typical values, per diode).

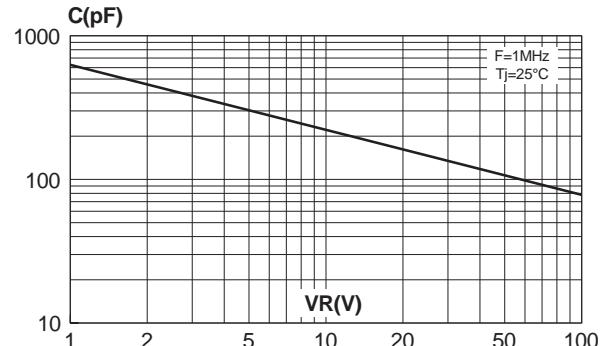


Fig. 9: Forward voltage drop versus forward current (maximum values, per diode).

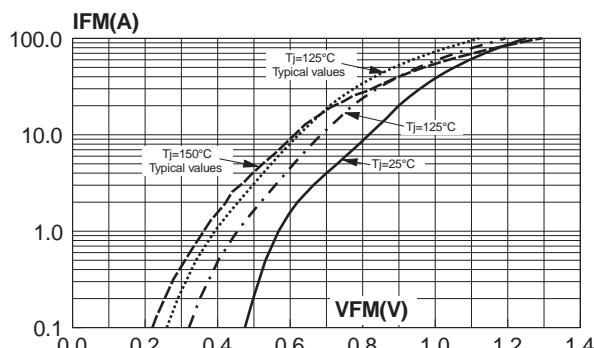
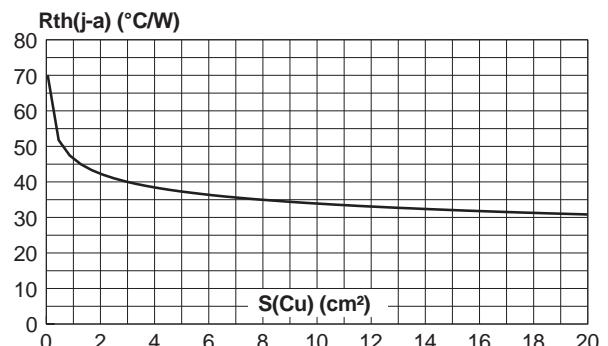


Fig. 10: Thermal resistance junction to ambient versus copper surface under tab (Epoxy printed circuit board FR4, copper thickness: $35\mu m$)



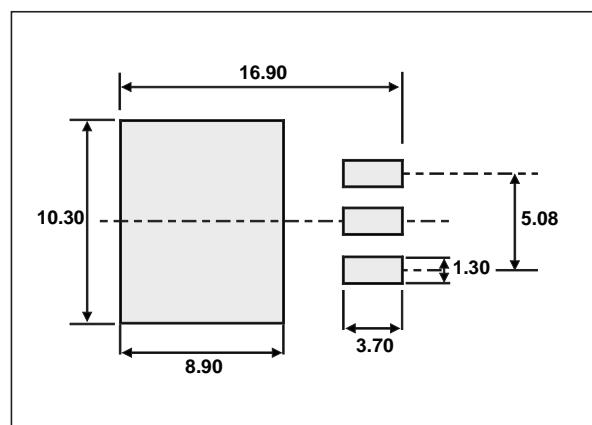
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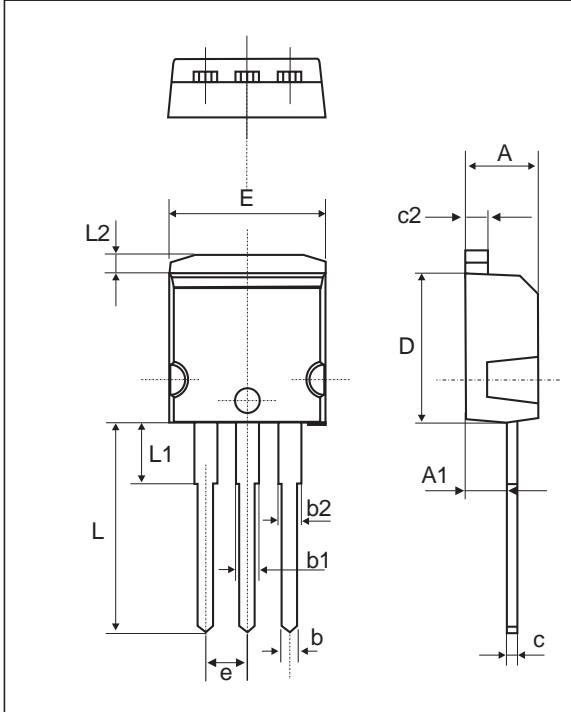
PACKAGE MECHANICAL DATA D²PAK

* FLAT ZONE NO LESS THAN 2mm

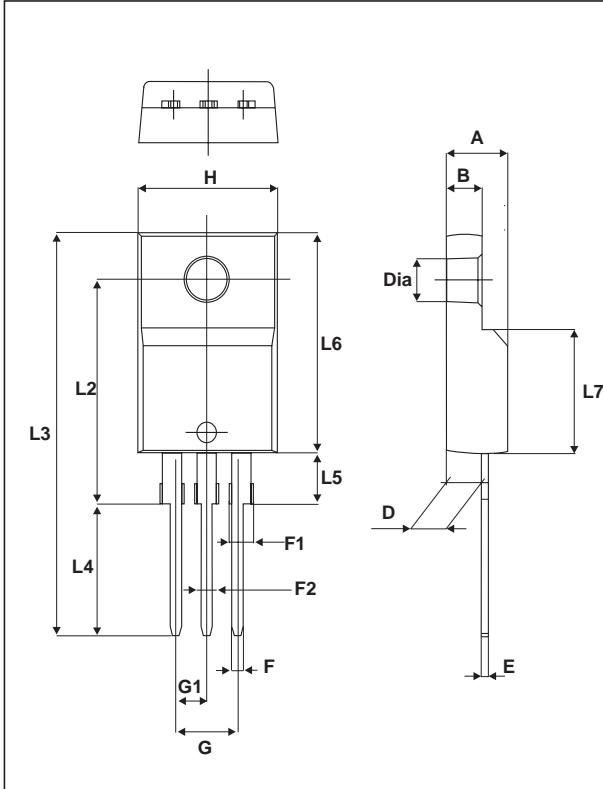
| REF. | DIMENSIONS | | | |
|------|-------------|-------|------------|-------|
| | Millimeters | | Inches | |
| | Min. | Max. | Min. | Max. |
| A | 4.40 | 4.60 | 0.173 | 0.181 |
| A1 | 2.49 | 2.69 | 0.098 | 0.106 |
| A2 | 0.03 | 0.23 | 0.001 | 0.009 |
| B | 0.70 | 0.93 | 0.027 | 0.037 |
| B2 | 1.14 | 1.70 | 0.045 | 0.067 |
| C | 0.45 | 0.60 | 0.017 | 0.024 |
| C2 | 1.23 | 1.36 | 0.048 | 0.054 |
| D | 8.95 | 9.35 | 0.352 | 0.368 |
| E | 10.00 | 10.40 | 0.393 | 0.409 |
| G | 4.88 | 5.28 | 0.192 | 0.208 |
| L | 15.00 | 15.85 | 0.590 | 0.624 |
| L2 | 1.27 | 1.40 | 0.050 | 0.055 |
| L3 | 1.40 | 1.75 | 0.055 | 0.069 |
| M | 2.40 | 3.20 | 0.094 | 0.126 |
| R | 0.40 typ. | | 0.016 typ. | |
| V2 | 0° | 8° | 0° | 8° |

FOOT PRINT in millimeters



PACKAGE MECHANICAL DATA
I²PAK


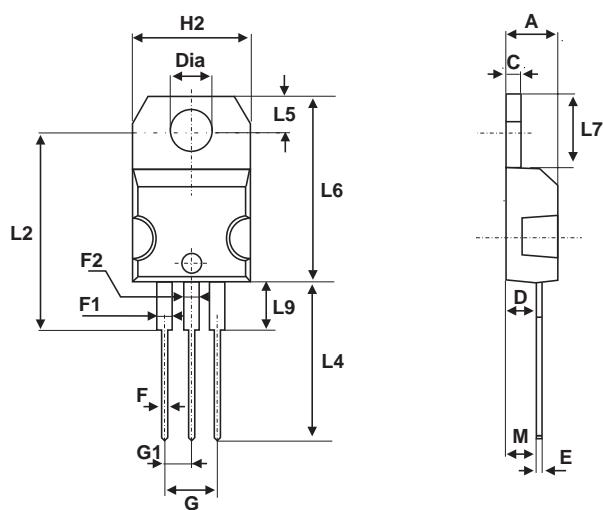
| REF. | DIMENSIONS | | | |
|------|-------------|------|--------|-------|
| | Millimeters | | Inches | |
| | Min. | Max. | Min. | Max. |
| A | 4.40 | 4.60 | 0.173 | 0.181 |
| A1 | 2.49 | 2.69 | 0.098 | 0.106 |
| b | 0.70 | 0.93 | 0.028 | 0.037 |
| b1 | 1.14 | 1.17 | 0.044 | 0.046 |
| b2 | 1.14 | 1.17 | 0.044 | 0.046 |
| c | 0.45 | 0.60 | 0.018 | 0.024 |
| c2 | 1.23 | 1.36 | 0.048 | 0.054 |
| D | 8.95 | 9.35 | 0.352 | 0.368 |
| e | 2.40 | 2.70 | 0.094 | 0.106 |
| E | 10.0 | 10.4 | 0.394 | 0.409 |
| L | 13.1 | 13.6 | 0.516 | 0.535 |
| L1 | 3.48 | 3.78 | 0.137 | 0.149 |
| L2 | 1.27 | 1.40 | 0.050 | 0.055 |

PACKAGE MECHANICAL DATA
TO-220FPAB


| REF. | DIMENSIONS | | | |
|------|-------------|------|-----------|-------|
| | Millimeters | | Inches | |
| | Min. | Max. | Min. | Max. |
| A | 4.4 | 4.6 | 0.173 | 0.181 |
| B | 2.5 | 2.7 | 0.098 | 0.106 |
| D | 2.5 | 2.75 | 0.098 | 0.108 |
| E | 0.45 | 0.70 | 0.018 | 0.027 |
| F | 0.75 | 1 | 0.030 | 0.039 |
| F1 | 1.15 | 1.70 | 0.045 | 0.067 |
| F2 | 1.15 | 1.70 | 0.045 | 0.067 |
| G | 4.95 | 5.20 | 0.195 | 0.205 |
| G1 | 2.4 | 2.7 | 0.094 | 0.106 |
| H | 10 | 10.4 | 0.393 | 0.409 |
| L2 | 16 Typ. | | 0.63 Typ. | |
| L3 | 28.6 | 30.6 | 1.126 | 1.205 |
| L4 | 9.8 | 10.6 | 0.386 | 0.417 |
| L5 | 2.9 | 3.6 | 0.114 | 0.142 |
| L6 | 15.9 | 16.4 | 0.626 | 0.646 |
| L7 | 9.00 | 9.30 | 0.354 | 0.366 |
| Dia. | 3.00 | 3.20 | 0.118 | 0.126 |

STPS10H100CT/CG/CR/CFP

PACKAGE MECHANICAL DATA TO-220AB



| REF. | DIMENSIONS | | | |
|-------|-------------|-------|------------|-------|
| | Millimeters | | Inches | |
| | Min. | Max. | Min. | Max. |
| A | 4.40 | 4.60 | 0.173 | 0.181 |
| C | 1.23 | 1.32 | 0.048 | 0.051 |
| D | 2.40 | 2.72 | 0.094 | 0.107 |
| E | 0.49 | 0.70 | 0.019 | 0.027 |
| F | 0.61 | 0.88 | 0.024 | 0.034 |
| F1 | 1.14 | 1.70 | 0.044 | 0.066 |
| F2 | 1.14 | 1.70 | 0.044 | 0.066 |
| G | 4.95 | 5.15 | 0.194 | 0.202 |
| G1 | 2.40 | 2.70 | 0.094 | 0.106 |
| H2 | 10 | 10.40 | 0.393 | 0.409 |
| L2 | 16.4 typ. | | 0.645 typ. | |
| L4 | 13 | 14 | 0.511 | 0.551 |
| L5 | 2.65 | 2.95 | 0.104 | 0.116 |
| L6 | 15.25 | 15.75 | 0.600 | 0.620 |
| L7 | 6.20 | 6.60 | 0.244 | 0.259 |
| L9 | 3.50 | 3.93 | 0.137 | 0.154 |
| M | 2.6 typ. | | 0.102 typ. | |
| Diam. | 3.75 | 3.85 | 0.147 | 0.151 |

- Cooling method: C.
- Recommended torque value: 0.55 m.N
- Maximum torque value 0.70 m.N

| Ordering type | Marking | Package | Weight | Base qty | Delivery mode |
|-----------------|---------------|--------------------|--------|----------|---------------|
| STPS10H100CT | STPS10H100CT | TO-220AB | 2.20g | 50 | Tube |
| STPS10H100CFP | STPS10H100CFP | TO-220FPAB | 2.0 g | 50 | Tube |
| STPS10H100CG | STPS10H100CG | D ² PAK | 1.48g | 50 | Tube |
| STPS10H100CG-TR | STPS10H100CG | D ² PAK | 1.48g | 1000 | Tape and reel |
| STPS10H100CR | STPS10H100CR | I ² PAK | 1.49g | 50 | Tube |

- Epoxy meets UL94,V0

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